

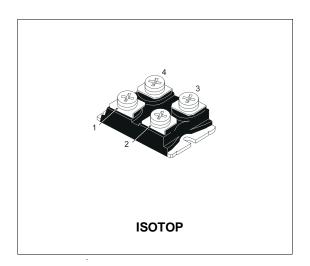
ESM2030DV

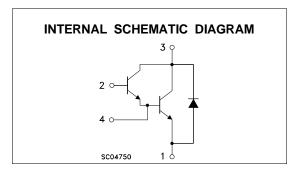
NPN DARLINGTON POWER MODULE

- HIGH CURRENT POWER BIPOLAR MODULE
- VERY LOW Rth JUNCTION CASE
- SPECIFIED ACCIDENTAL OVERLOAD AREAS
- ULTRAFAST FREEWHEELING DIODE
- FULLY INSULATED PACKAGE (UL COMPLIANT)
- EASY TO MOUNT
- LOW INTERNAL PARASITIC INDUCTANCE

INDUSTRIAL APPLICATIONS:

- MOTOR CONTROL
- UPS
- DC/DC & DC/AC CONVERTERS





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CEV}	Collector-Emitter Voltage (V _{BE} = -5 V)	400	V
V _{CEO(sus)}	Collector-Emitter Voltage (I _B = 0)	300	V
V_{EBO}	Emitter-Base Voltage (I _C = 0)	7	V
Ic	Collector Current	67	А
I _{CM}	Collector Peak Current (t _p = 10 ms)	100	A
I _B	Base Current	3	А
I _{BM}	Base Peak Current (t _p = 10 ms)	6	A
P _{tot}	Total Dissipation at T _c = 25 °C	150	W
V _{isol}	Insulation Withstand Voltage (RMS) from All Four Terminals to Exernal Heatsink	2500	V
T _{stg}	Storage Temperature	-55 to 150	°C
Tj	Max. Operating Junction Temperature	150	°C

September 2003

THERMAL DATA

R _{thj-case} R _{thi-case}	Thermal Resistance Junction-case Thermal Resistance Junction-case	,	0.83 1.2	°C/W	
R _{thc-h}	Thermal Resistance Case-heatsine	` ,		0, 11	
	Grease Applied	Max	0.05	°C/W	

ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CER} #	Collector Cut-off Current ($R_{BE} = 5 \Omega$)	V _{CE} = V _{CEV} V _{CE} = V _{CEV} T _j = 100 °C			1.5 16	mA mA
I _{CEV} #	Collector Cut-off Current (V _{BE} = -5V)	$V_{CE} = V_{CEV}$ $V_{CE} = V_{CEV}$ $T_j = 100$ °C			1 11	mA mA
I _{EBO} #	Emitter Cut-off Current (I _C = 0)	V _{EB} = 5 V			1	mA
V _{CEO(SUS)} *	Collector-Emitter Sustaining Voltage	$I_C = 0.2 \text{ A}$ L = 25 mH $V_{clamp} = 300 \text{ V}$	300			V
h _{FE} *	DC Current Gain	Ic = 56 A VcE = 5 V		300		
V _{CE(sat)} *	Collector-Emitter Saturation Voltage	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$		1.25 1.4 1.5 1.8	1.8	V V V
$V_{BE(sat)^*}$	Base-Emitter Saturation Voltage	I _C = 56 A I _B = 1.6 A I _C = 56 A I _B = 1.6 A T _j = 100 °C		2.4 2.5	3	V V
di _C /dt	Rate of Rise of On-state Collector	$V_{CC} = 300 \text{ V}$ $R_C = 0$ $t_p = 3 \mu s$ $I_{B1} = 0.6 \text{ A}$ $T_j = 100 ^{\circ}\text{C}$	220	260		A/μs
V _{CE} (3 μs)••	Collector-Emitter Dynamic Voltage	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$		3	6	V
V _{CE} (5 μs)••	Collector-Emitter Dynamic Voltage	$V_{CC} = 300 \text{ V}$ $R_C = 7.5 \Omega$ $I_{B1} = 0.6 \text{ A}$ $T_j = 100 ^{\circ}\text{C}$		2.2	4	V
t _s t _f t _c	Storage Time Fall Time Cross-over Time	$\begin{array}{lll} I_{C} = 40 \; A & V_{CC} = 50 \; V \\ V_{BB} = -5 \; V & R_{BB} = 0.6 \; \Omega \\ V_{clamp} = 300 \; V & I_{B1} = 0.4 \; A \\ L = 0.06 \; mH & T_{j} = 100 \; ^{\circ}C \end{array}$		2 0.35 0.8	3 0.6 1.2	μs μs μs
V _{CEW}	Maximum Collector Emitter Voltage Without Snubber	$\begin{array}{lll} I_{CWoff} = 67 \; A & I_{B1} = 1.6 \; A \\ V_{BB} = -5 \; V & V_{CC} = 50 \; V \\ L = 0.037 \; mH & R_{BB} = 0.6 \; \Omega \\ T_{j} = 125 \; ^{\circ}C & \end{array}$	300			V
V _F *	Diode Forward Voltage	I _F = 56 A T _j = 100 °C		1.15	1.6	V
I _{RM}	Reverse Recovery Current	$V_{CC} = 200 \text{ V}$ $I_F = 56 \text{ A}$ $di_F/dt = -220 \text{ A}/\mu\text{s}$ $L < 0.05 \mu\text{H}$ $T_j = 100 ^{\circ}\text{C}$		12	17	A

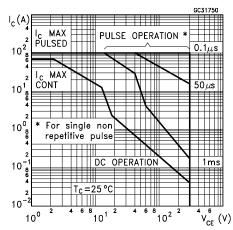
^{*} Pulsed: Pulse duration = 300 μ s, duty cycle 1.5 %

[#] See test circuit in databook introduction

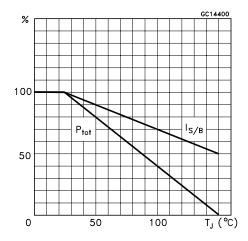
To evaluate the conduction losses of the diode use the following equations:

 $V_F = 1.1 + 0.0045 I_F$ $P = 1.1 I_{F(AV)} + 0.0045 I_{F(RMS)}^2$

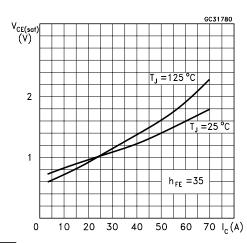
Safe Operating Areas



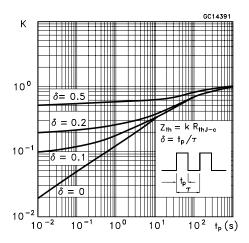
Derating Curve



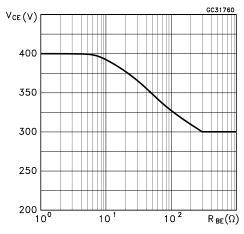
Collector Emitter Saturation Voltage



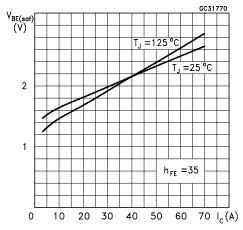
Thermal Impedance



Collector-emitter Voltage Versus base-emitter Resistance

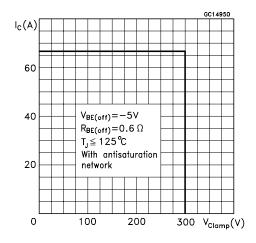


Base-Emitter Saturation Voltage

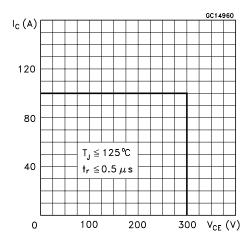


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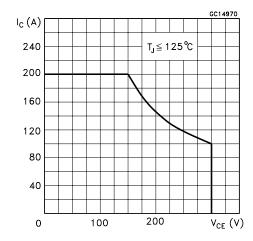
Reverse Biased SOA



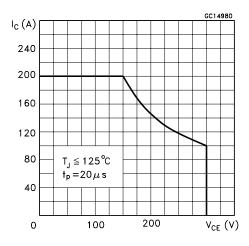
Foward Biased SOA



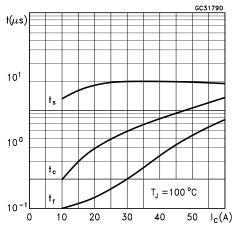
Reverse Biased AOA



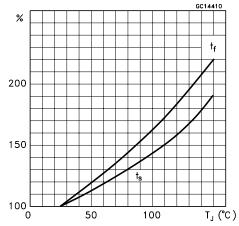
Forward Biased AOA



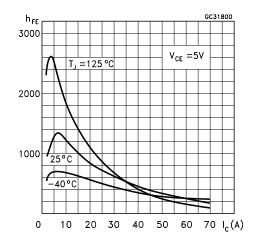
Switching Times Inductive Load



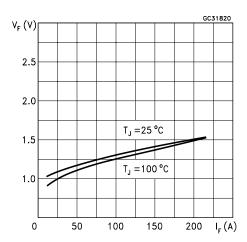
Switching Times Inductive Load Versus Temperature



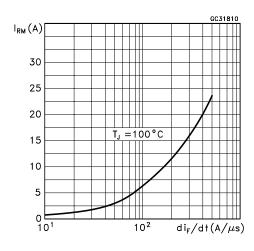
Dc Current Gain



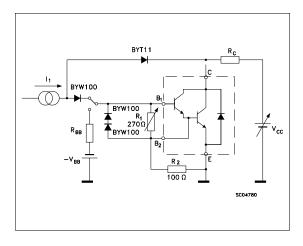
Typical V_F Versus I_F



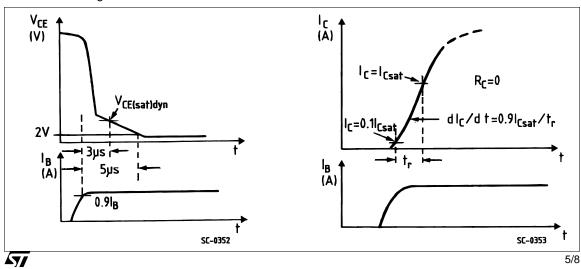
Peak Reverse Current Versus di_F/dt



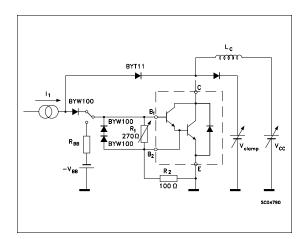
Turn-on Switching Test Circuit



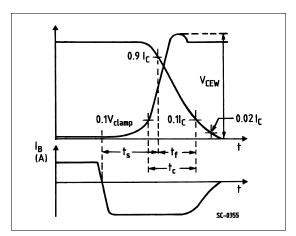
Turn-on Switching Waveforms



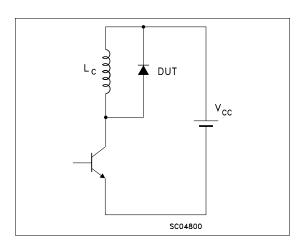
Turn-on Switching Test Circuit



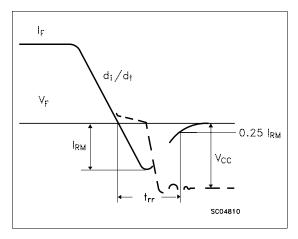
Turn-off Switching Waveforms



Turn-off Switching Test Circuit of Diode

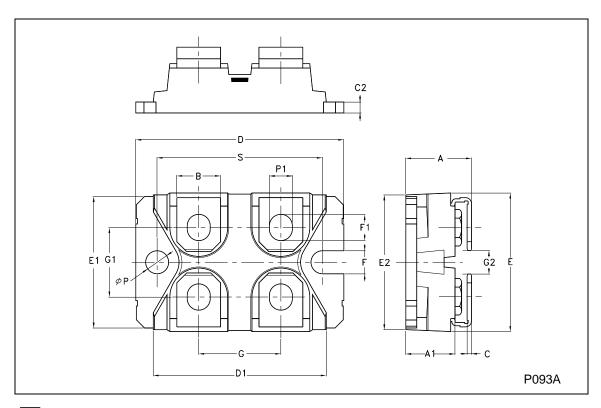


Turn-off Switching Waveform of Diode



ISOTOP MECHANICAL DATA

DIM.	mm		inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
Α	11.8		12.2	0.465		0.480
A1	8.9		9.1	0.350		0.358
В	7.8		8.2	0.307		0.322
С	0.75		0.85	0.029		0.033
C2	1.95		2.05	0.076		0.080
D	37.8		38.2	1.488		1.503
D1	31.5		31.7	1.240		1.248
Е	25.15		25.5	0.990		1.003
E1	23.85		24.15	0.938		0.950
E2		24.8			0.976	
G	14.9		15.1	0.586		0.594
G1	12.6		12.8	0.496		0.503
G2	3.5		4.3	0.137		1.169
F	4.1		4.3	0.161		0.169
F1	4.6		5	0.181		0.196
Р	4		4.3	0.157		0.169
P1	4		4.4	0.157		0.173
S	30.1		30.3	1.185		1.193



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